

### DESCRIPTION:

The JOC308XD4 series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a monolithic silicon zero-cross photo triac in a plastic DIP4 package with different lead forming options. The products are widely used

3 0 Td 3nsteoliel Tc 0 Tw ( )Tj -/004 Tc -0.002 Tw 0.33 05Td [(wi)-10vusyvusiaits Tc 0 Tw ( )Tj 672 [

	Power Dissipation Derating ( $T_a$ 125 )	$\bullet P_{D/}$	-3.33	mW/
Total Power Dissipation		$P_{tot}$	350	mW
Isolation Voltage		$V_{iso}$	5000'	Vrms
Operating Temperature		$T_{opr}$	-55~100	
Storage Temperature		$T_{stg}$	-55~125	
Soldering Temperature		$T_{sol}$	260 <sup>8</sup>	

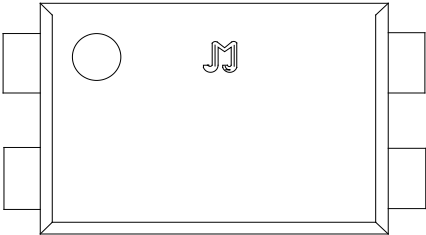
NOTE1AC for 1minute, R.H.=40~60%

NOTE2For 10 seconds

ELECTRICAL CHARACTERISTICS (T<sub>J</sub> 0 T<sub>c</sub> 0 T<sub>w</sub> 1.43 0 T<sub>d</sub> ( ) T<sub>j</sub> EMC /P <</MCID 50

ORDERING AND MARKING INFORMATION

MARKING INFORMATION



## Characteristics Curves

FIG.1: Forward Current vs. Ambient Temperature

FIG.2: On-state Terminal Current vs. Ambient Temperature

FIG.7: Normalized On-state Terminal Voltage vs. Ambient Temperature



FIG.8: On-state Terminal Voltage vs. On-state Terminal Current

TEST CIRCUITS

FIG.12: Test Circuits of Turn On Time

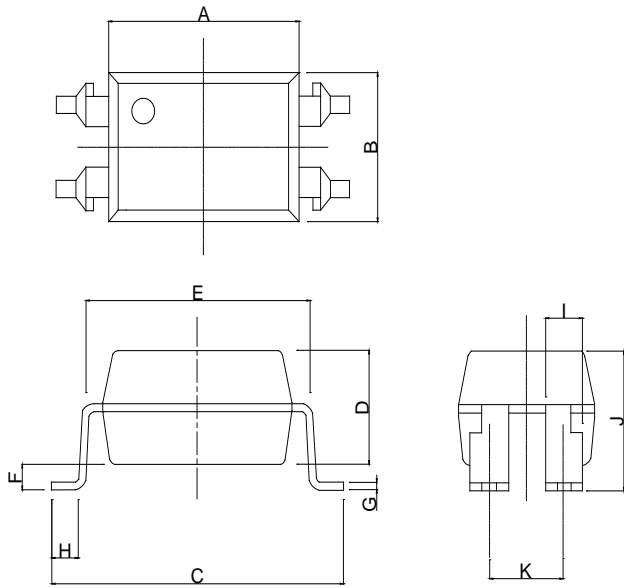
FIG.13: Waveforms of Turn On Time

Fig.14: Test Circuits of dV/dt

Fig.15: Waveforms of dV/dt

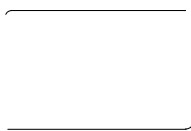


Option S Type:

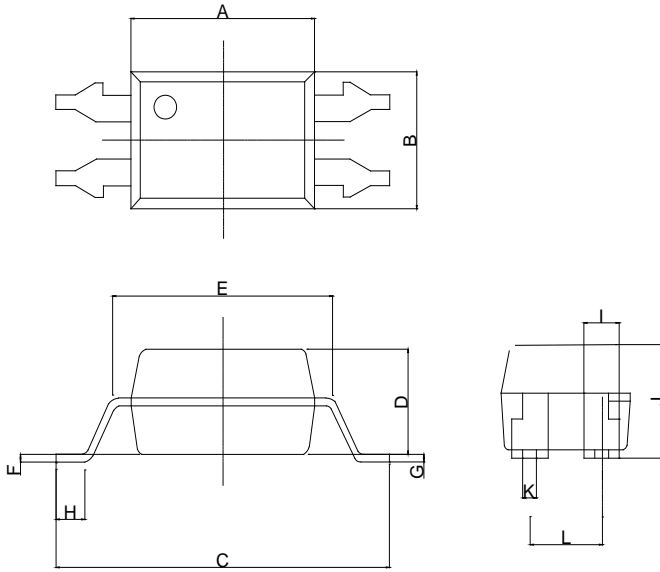


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	6.30		6.70	0.249		0.265
B	4.38		4.78	0.173		0.189
C	9.85		10.45	0.389		0.413
D	3.30		3.70	0.130		0.146
E	7.32		7.92	0.289		0.313
F		0.80			0.032	
G		0.25			0.010	
H		0.80			0.032	
I	1.20		1.40	0.047		0.055
J	4.00		4.60	0.158		0.182
K		2.54			0.100	

Option SL Type:



Option S LM Type:

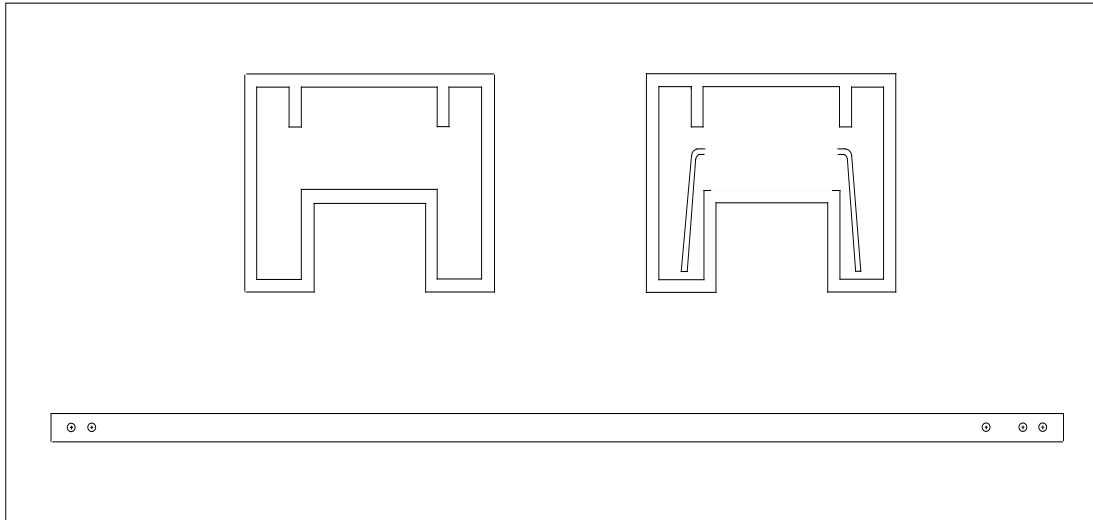


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	6.30		6.70	0.248		0.264
B	4.38		4.78	0.172		0.188
C	11.50		12.10	0.453		0.476
D	3.30		3.70	0.130		0.146
E	7.32		7.92	0.288		0.312
F						
G						
H	0.40			0.016		
I	1.20		1.40	0.047		0.055
J	3.45		4.05	0.136		0.159
K						
L						

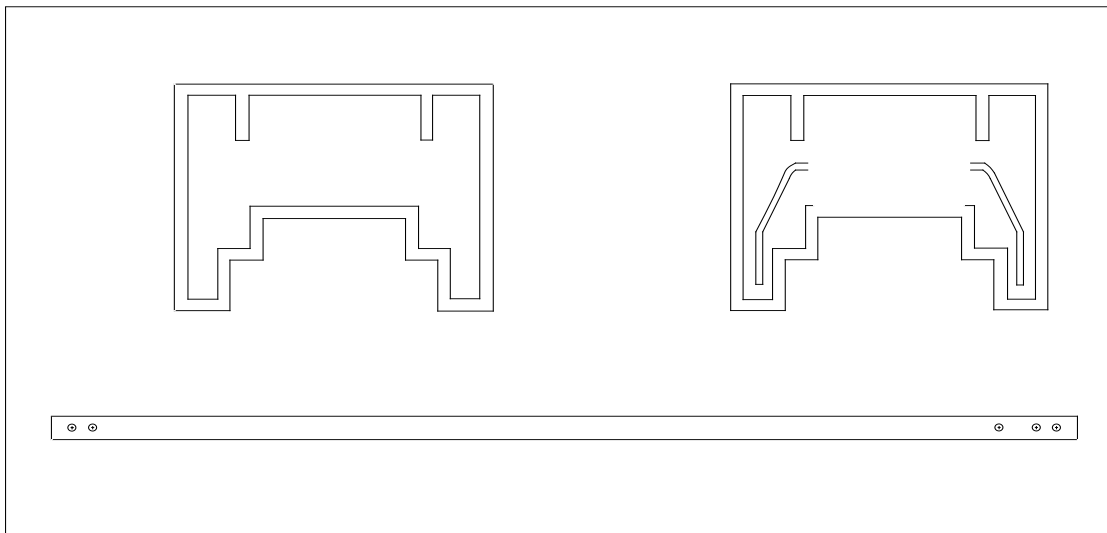


TUBE SPECIFICATIONS (Dimensions in mm unless otherwise stated)

Standard DIP



Option M

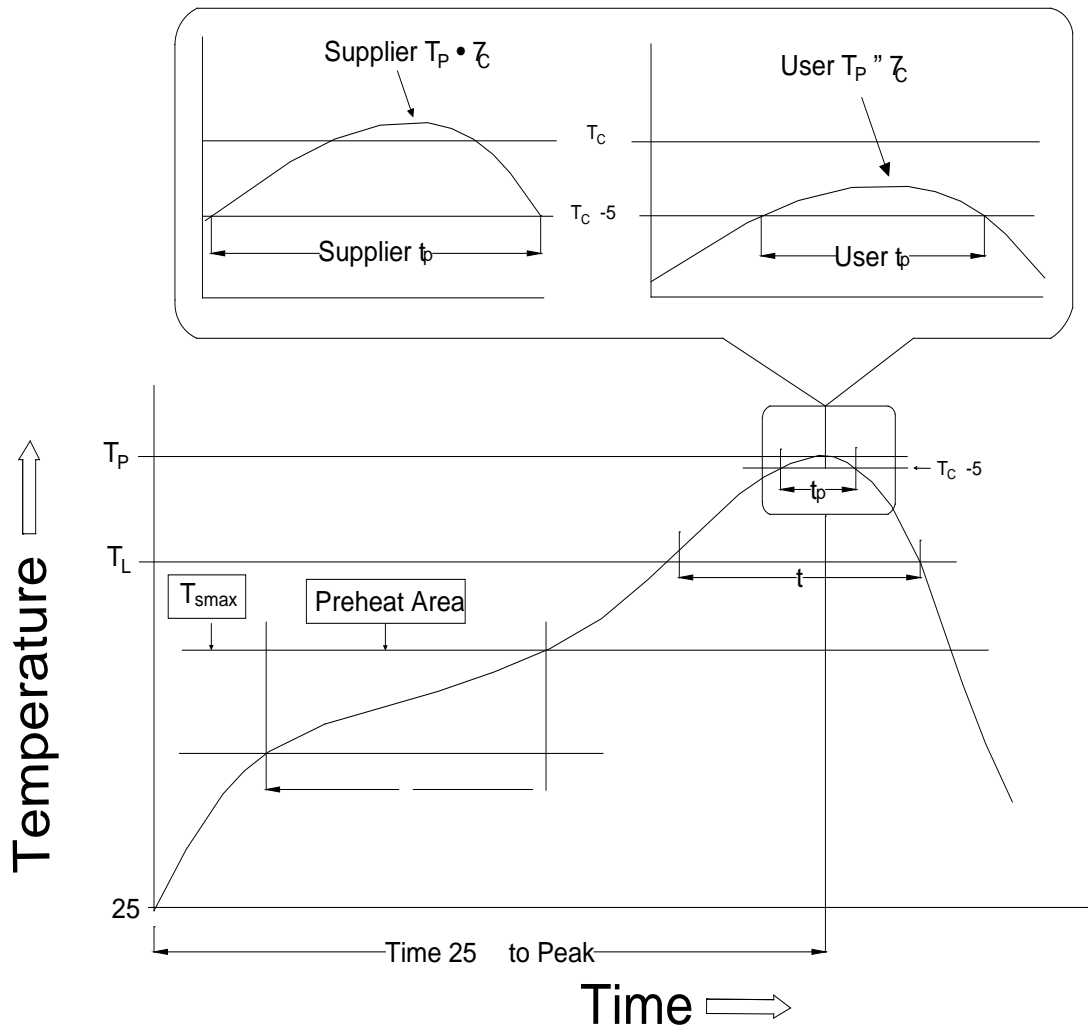




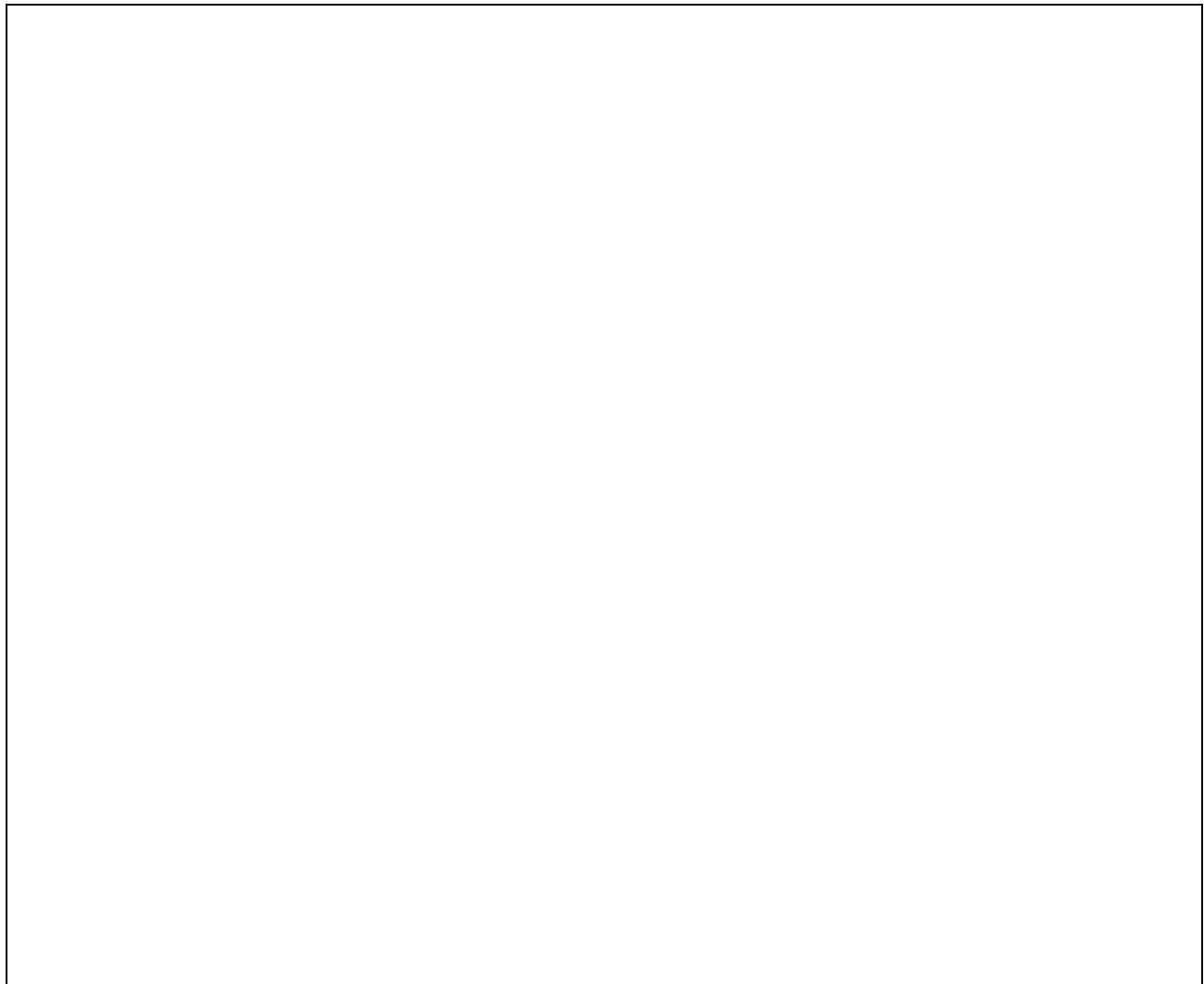
Option SL(T3)

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
D0						
P0						
P1		12.00			0.472	
P2						
E		1.75			0.069	
F		7.50				
T		0.40			0.016	
W		16.00			0.630	

REFLOW INFORMATION



## WAVE SOLDERING



## HAND SOLDERING BY SOLDERING IRON

Soldering Temperature	360 5
Soldering Time	3s max.

## Document Revision History

Date	Revision	Changes
Apr.2, 2025	A.1.0	Last update
Nov.5, 2025	A.1.1	Add SLM package

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